

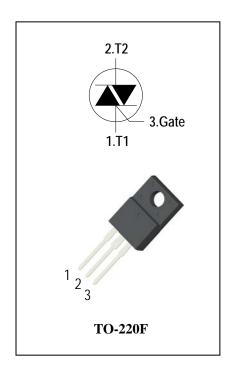
### 3 Quadrants Triacs

### **General Description**

High current density due to mesa technology .the ADT12C triac series is suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, High power motor controls e.g. washing machines and vacuum cleaners,Rectifier-fed DC inductive loads e.g.DC motors and solenoids , motor speed controllers.

### **Features**

- ◆ Repetitive Peak Off-State Voltage: 600Vand800V
- ◆ R.M.S On-State Current ( I<sub>T(RMS)</sub>=12A )
- ◆ High Commutation dv/dt
- ◆ These Devices are Pb-Free and are RoHS Compliant
- ◆ Isolation Voltage(V<sub>ISO</sub>=1500V AC)



### **Absolute Maximum Ratings**

Symbol	Items	Conditions		Ratings	Unit
$V_{DRM}$	Denotitive Deak Off State Voltage	Ti = 25°C	ADT12C60F	600	V
$V_{RRM}$	Repetitive Peak Off-State Voltage	Tj = 25°C	ADT12C80F	800	V
$I_{T(RMS)}$	R.M.S On-State Current	T <sub>C</sub> = 90°C		12	Α
I <sub>TSM</sub>	Surge On-State Current	tp=20ms(50Hz)/tp=16.7ms(60Hz)		140/146	Α
l <sup>2</sup> t	I <sup>2</sup> t for fusing	tp=10ms		78	A <sup>2</sup> s
-11/-14	Critical rate of rise of on-state	F = 120 Hz Tj = 125°C	50	A/µs	
dl/dt	current	I <sub>G</sub> = 2 x I <sub>GT</sub> , tr ≤ 100 ns			
$I_{GM}$	Peak Gate Current	tp = 20 μs Tj = 125°C		4	Α
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=125°C)			1	W
$P_GM$	Peak Gate Power Dissipation(tp=20us,Tj=125°C)			10	W
Tj	Operating Junction Temperature			- 40 ~ 125	°C
$T_{STG}$	Storage Temperature			- 40 ~ 150	°C



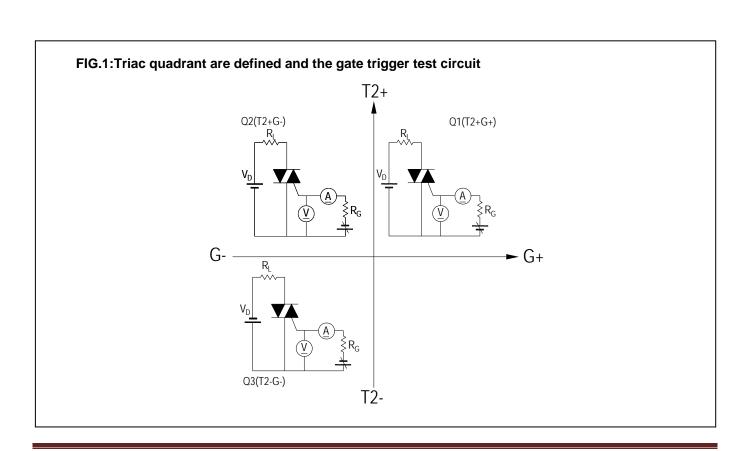


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### **Electrical Characteristics** (Tj = 25°C unless otherwise specified)

Symbol	Items	Conditions		ADT12C60F/80F			=	Unit	
					Т	S	Blank	В	
I <sub>DRM</sub>	Peak Forward Reverse Blocking		$V_{DRM} = V_{RRM}$ , $Tj = 25$ °C	Max	5			uA	
I <sub>RRM</sub>	Current		$V_{DRM} = V_{RRM}$ , $Tj = 125$ °C	Max.	1			mA	
V <sub>TM</sub>	Peak On-S	tate Voltage	I <sub>TM</sub> = 17A, t <sub>p</sub> = 380 μs	Max.	1.55		V		
$V_{GD}$	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 125^{\circ}\text{C}$	Min.	0.2		V		
$V_{GT}$	Q1-Q2-Q3	Gate Trigger Voltage	V 40V D 220	Max. 1.3			V		
I <sub>GT</sub>	Q1-Q2-Q3	Gate Trigger Current	$V_D = 12V$ , $R_L = 33\Omega$	Max.	5	10	35	50	mA
I <sub>H</sub>	Q1-Q2-Q3	Holding Current	I <sub>T</sub> = 0.1A	Max.	10	15	35	50	mA
	Q1-Q3	Latabina Current	1 - 121	Max.	10	25	50	70	mA
IL	Q2	Latching Current	$I_G = 1.2 I_{GT}$		15	30	70	80	
dV/dt	Critical Rate of Rise of Off-State  Voltage		$V_D = 2/3V_{DRM}$ gate open Tj = 125°C	Min.	20	40	500	1000	V/µs
(dV/dt)c	Rate of Change of Commutating  Current,		(dl/dt)c=-5.3A/ms Tj = 125°C	Min.	0.5	1	10	25	V/µs
R <sub>th(j-c)</sub>	Junction to case (AC)		Max.	2.3			°C/W		
R <sub>th(j-a)</sub>	Junction to ambient		Max.	60			°C/W		



# **ADV**

FIG.2: Maximum on-state power dissipation

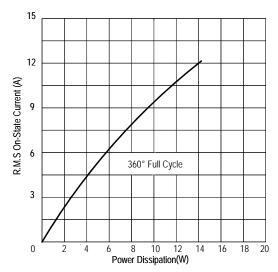


FIG.4: Maximum transient thermal impedance

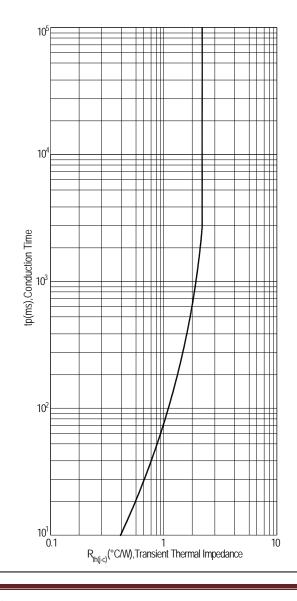


FIG.3: Typical RMS on-state current VS Allowable case Temperature

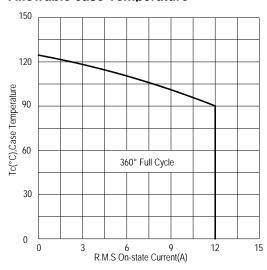


FIG.5: Rated surge on-state current (Non-Repetitive)

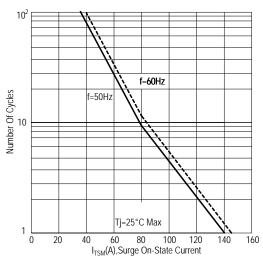


FIG.6: Gate trigger current VS Junction temperature

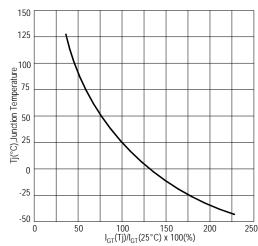






FIG.7:Holding current and Latching current VS Junction temperature

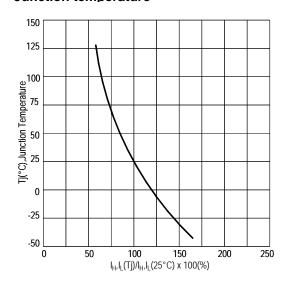


FIG.8: Gate trigger voltage VS Junction temperature

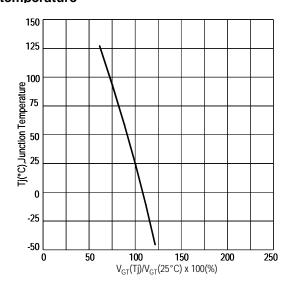
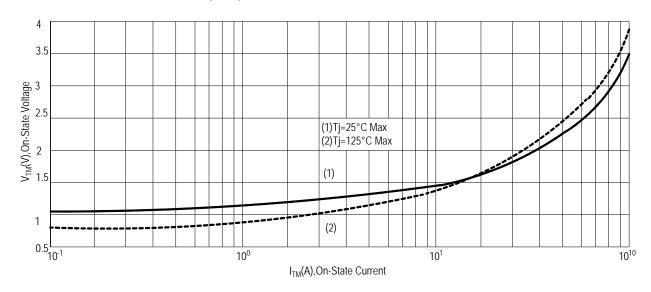


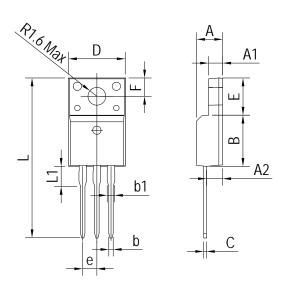
FIG.9: On-state characteristics(Max)



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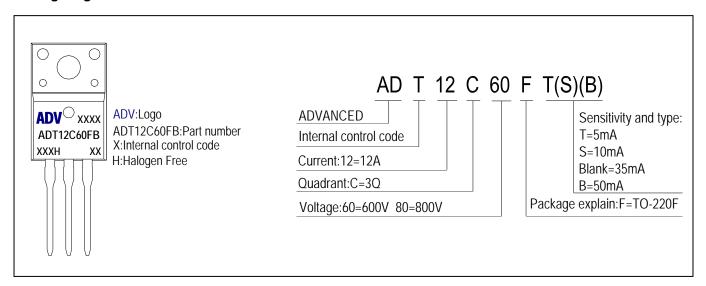


## PACKAGE MECHANICAL DATA TO-220F Package Dimension



Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min Max		Min	Max	
А	4.300	4.800	0.169	0.189	
A1	2.400	2.700	0.094	0.106	
A2	2.500	3.000	0.098	0.118	
В	8.800	9.300	0.346	0.367	
b	0.600	0.950	0.023	0.037	
b1	1.100	1.700	0.043	0.067	
С	0.500	0.750	0.020	0.030	
D	9.700	10.360	0.382	0.408	
Е	6.400	6.800	0.252	0.268	
е	2.540 TYP		0.100 TYP		
F	3.300 REF		0.130 REF		
L	28.000	30.000	1.102	1.181	
L1	2.900	3.630	0.114	0.143	

### **Making Diagram**



### **Ordering information**

Part number	Package	Marking	Packing	Quantity			
ADT12C60F#	TO-220F	ADT12C60F#	Tube	50pcs			
ADT12C80F#	TO-220F	ADT12C80F#	Tube	50pcs			
Note:# = Gate Trigger Current Sensitivity and type							



### ADT12C60F/80F

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